

# BAV99 series

## High-speed switching diodes

Rev. 05 — 20 August 2008

Product data sheet

## 1. Product profile

### 1.1 General description

High-speed switching diodes, encapsulated in small Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package			Configuration	Package configuration
	NXP	JEITA	JEDEC		
BAV99	SOT23	-	TO-236AB	dual series	small
BAV99S	SOT363	SC-88	-	quadruple; 2 series	very small
BAV99W	SOT323	SC-70	-	dual series	very small

### 1.2 Features

- High switching speed:  $t_{rr} \leq 4$  ns
- Low leakage current
- Small SMD plastic packages
- Low capacitance:  $C_d \leq 1.5$  pF
- Reverse voltage:  $V_R \leq 100$  V

### 1.3 Applications

- High-speed switching
- General-purpose switching
- Reverse polarity protection

### 1.4 Quick reference data

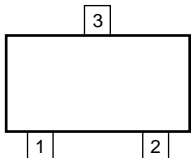
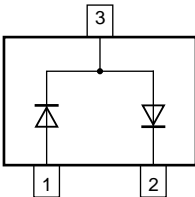
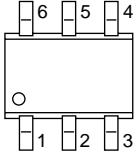
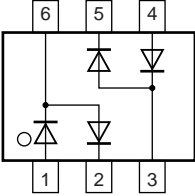
Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per diode</b>						
$I_R$	reverse current	$V_R = 80$ V	-	-	0.5	$\mu$ A
$V_R$	reverse voltage		-	-	100	V
$t_{rr}$	reverse recovery time		[1]	-	4	ns

[1] When switched from  $I_F = 10$  mA to  $I_R = 10$  mA;  $R_L = 100$   $\Omega$ ; measured at  $I_R = 1$  mA.

## 2. Pinning information

**Table 3. Pinning**

Pin	Description	Simplified outline	Graphic symbol
<b>BAV99; BAV99W</b>			
1	anode (diode 1)	 <p>006aaa144</p>	 <p>006aaa763</p>
2	cathode (diode 2)		
3	cathode (diode 1), anode (diode 2)		
<b>BAV99S</b>			
1	anode (diode 1)		 <p>006aab101</p>
2	cathode (diode 2)		
3	cathode (diode 3), anode (diode 4)		
4	anode (diode 3)		
5	cathode (diode 4)		
6	cathode (diode 1), anode (diode 2)		

## 3. Ordering information

**Table 4. Ordering information**

Type number	Package		Version
	Name	Description	
BAV99	-	plastic surface-mounted package; 3 leads	SOT23
BAV99S	SC-88	plastic surface-mounted package; 6 leads	SOT363
BAV99W	SC-70	plastic surface-mounted package; 3 leads	SOT323

## 4. Marking

**Table 5. Marking codes**

Type number	Marking code <sup>[1]</sup>
BAV99	A7*
BAV99S	K1*
BAV99W	A7*

[1] \* = -: made in Hong Kong  
 \* = p: made in Hong Kong  
 \* = t: made in Malaysia  
 \* = W: made in China

## 5. Limiting values

**Table 6. Limiting values**

*In accordance with the Absolute Maximum Rating System (IEC 60134).*

Symbol	Parameter	Conditions	Min	Max	Unit	
<b>Per diode</b>						
$V_{RRM}$	repetitive peak reverse voltage		-	100	V	
$V_R$	reverse voltage		-	100	V	
$I_F$	forward current					
		BAV99	[1]	-	215	mA
			[2]	-	125	mA
		BAV99S	[1]	-	200	mA
		BAV99W	[1]	-	150	mA
			[2]	-	130	mA
$I_{FRM}$	repetitive peak forward current		-	500	mA	
$I_{FSM}$	non-repetitive peak forward current	square wave	[3]			
		$t_p = 1 \mu\text{s}$	-	4	A	
		$t_p = 1 \text{ms}$	-	1	A	
		$t_p = 1 \text{s}$	-	0.5	A	
$P_{tot}$	total power dissipation		[1][4]			
		BAV99	$T_{amb} \leq 25 \text{ }^\circ\text{C}$	-	250	mW
		BAV99S	$T_{amb} \leq 85 \text{ }^\circ\text{C}$	[5]	250	mW
		BAV99W	$T_{amb} \leq 25 \text{ }^\circ\text{C}$	-	200	mW
<b>Per device</b>						
$T_j$	junction temperature		-	150	$^\circ\text{C}$	
$T_{amb}$	ambient temperature		-65	+150	$^\circ\text{C}$	
$T_{stg}$	storage temperature		-65	+150	$^\circ\text{C}$	

[1] Single diode loaded.

[2] Double diode loaded.

[3]  $T_j = 25 \text{ }^\circ\text{C}$  prior to surge.

[4] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[5] Soldering points at pins 2, 3, 5 and 6.

## 6. Thermal characteristics

**Table 7. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]			
	BAV99		-	-	500	K/W
	BAV99W		-	-	625	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point					
	BAV99		-	-	360	K/W
	BAV99S		[3]	-	260	K/W
	BAV99W		-	-	300	K/W

[1] Single diode loaded.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Soldering points at pins 2, 3, 5 and 6.

## 7. Characteristics

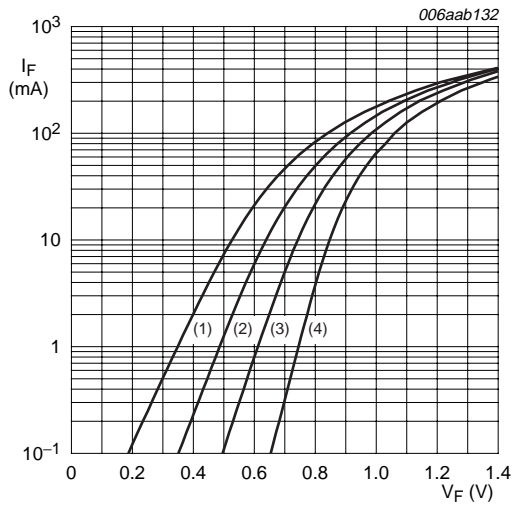
**Table 8. Characteristics**

$T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per diode</b>						
$V_F$	forward voltage	$I_F = 1\text{ mA}$	-	-	715	mV
		$I_F = 10\text{ mA}$	-	-	855	mV
		$I_F = 50\text{ mA}$	-	-	1	V
		$I_F = 150\text{ mA}$	-	-	1.25	V
$I_R$	reverse current	$V_R = 25\text{ V}$	-	-	30	nA
		$V_R = 80\text{ V}$	-	-	0.5	$\mu\text{A}$
		$V_R = 25\text{ V}; T_j = 150\text{ }^{\circ}\text{C}$	-	-	30	$\mu\text{A}$
		$V_R = 80\text{ V}; T_j = 150\text{ }^{\circ}\text{C}$	-	-	50	$\mu\text{A}$
$C_d$	diode capacitance	$f = 1\text{ MHz}; V_R = 0\text{ V}$	-	-	1.5	pF
$t_{rr}$	reverse recovery time		[1]	-	4	ns
$V_{FR}$	forward recovery voltage		[2]	-	1.75	V

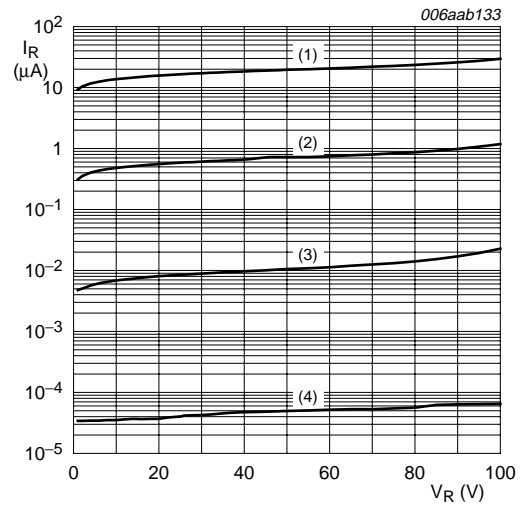
[1] When switched from  $I_F = 10\text{ mA}$  to  $I_R = 10\text{ mA}$ ;  $R_L = 100\text{ }\Omega$ ; measured at  $I_R = 1\text{ mA}$ .

[2] When switched from  $I_F = 10\text{ mA}$ ;  $t_r = 20\text{ ns}$ .



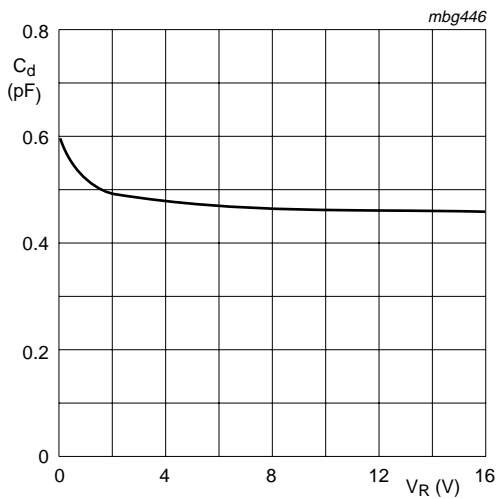
- (1)  $T_{amb} = 150^\circ\text{C}$
- (2)  $T_{amb} = 85^\circ\text{C}$
- (3)  $T_{amb} = 25^\circ\text{C}$
- (4)  $T_{amb} = -40^\circ\text{C}$

**Fig 1. Forward current as a function of forward voltage; typical values**



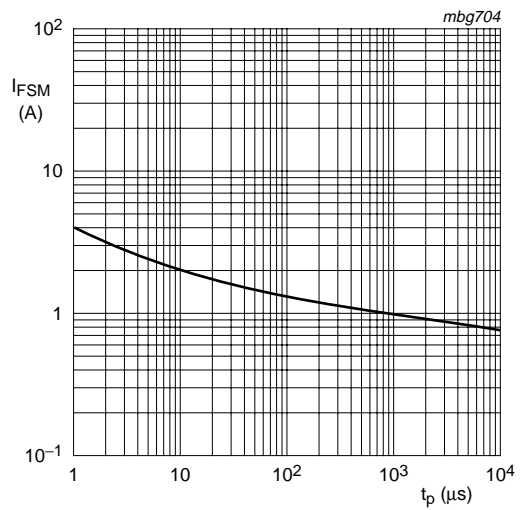
- (1)  $T_{amb} = 150^\circ\text{C}$
- (2)  $T_{amb} = 85^\circ\text{C}$
- (3)  $T_{amb} = 25^\circ\text{C}$
- (4)  $T_{amb} = -40^\circ\text{C}$

**Fig 2. Reverse current as a function of reverse voltage; typical values**



$f = 1\text{ MHz}; T_{amb} = 25^\circ\text{C}$

**Fig 3. Diode capacitance as a function of reverse voltage; typical values**

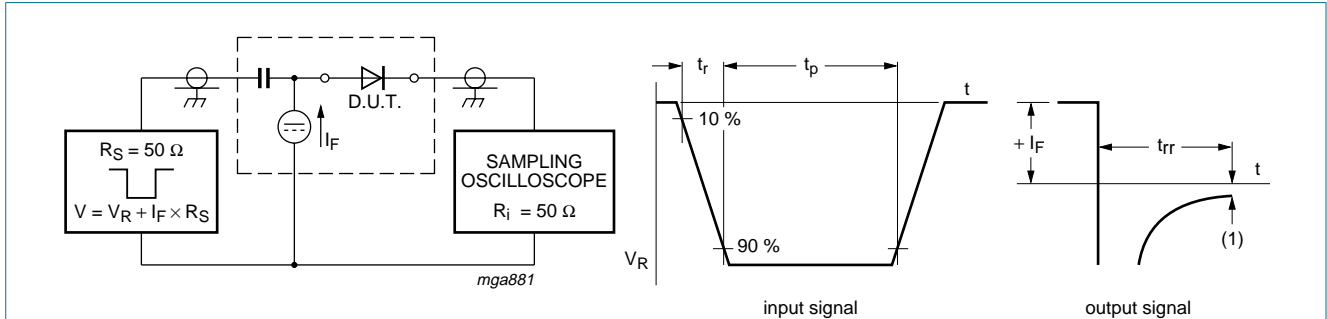


Based on square wave currents.

$T_j = 25^\circ\text{C}$ ; prior to surge

**Fig 4. Non-repetitive peak forward current as a function of pulse duration; maximum values**

**8. Test information**

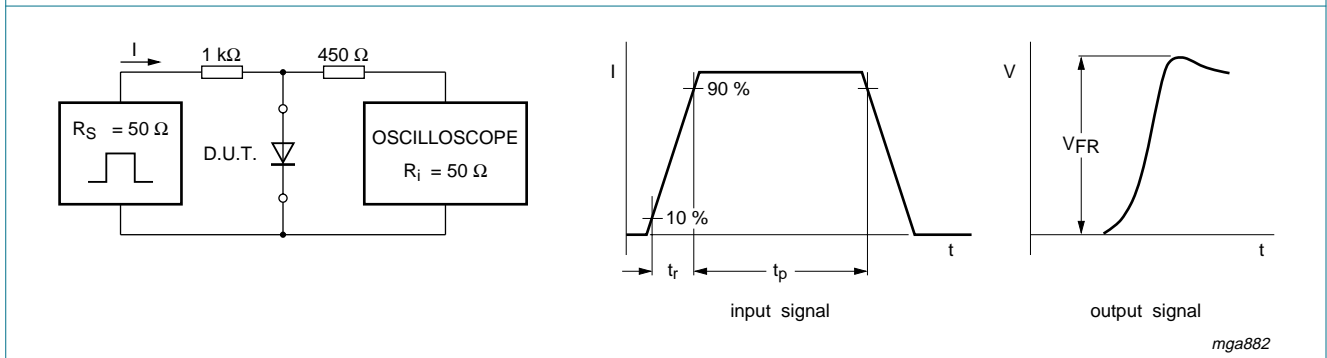


(1)  $I_R = 1 \text{ mA}$

Input signal: reverse pulse rise time  $t_r = 0.6 \text{ ns}$ ; reverse voltage pulse duration  $t_p = 100 \text{ ns}$ ; duty cycle  $\delta = 0.05$

Oscilloscope: rise time  $t_r = 0.35 \text{ ns}$

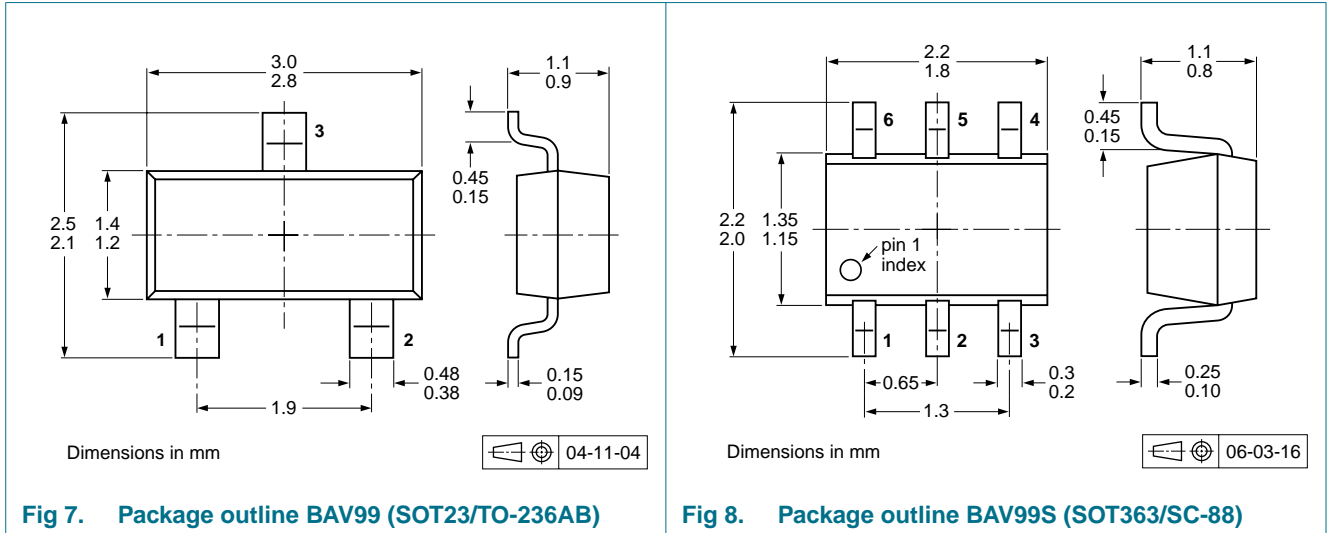
**Fig 5. Reverse recovery time test circuit and waveforms**



Input signal: forward pulse rise time  $t_r = 20 \text{ ns}$ ; forward current pulse duration  $t_p \geq 100 \text{ ns}$ ; duty cycle  $\delta \leq 0.005$

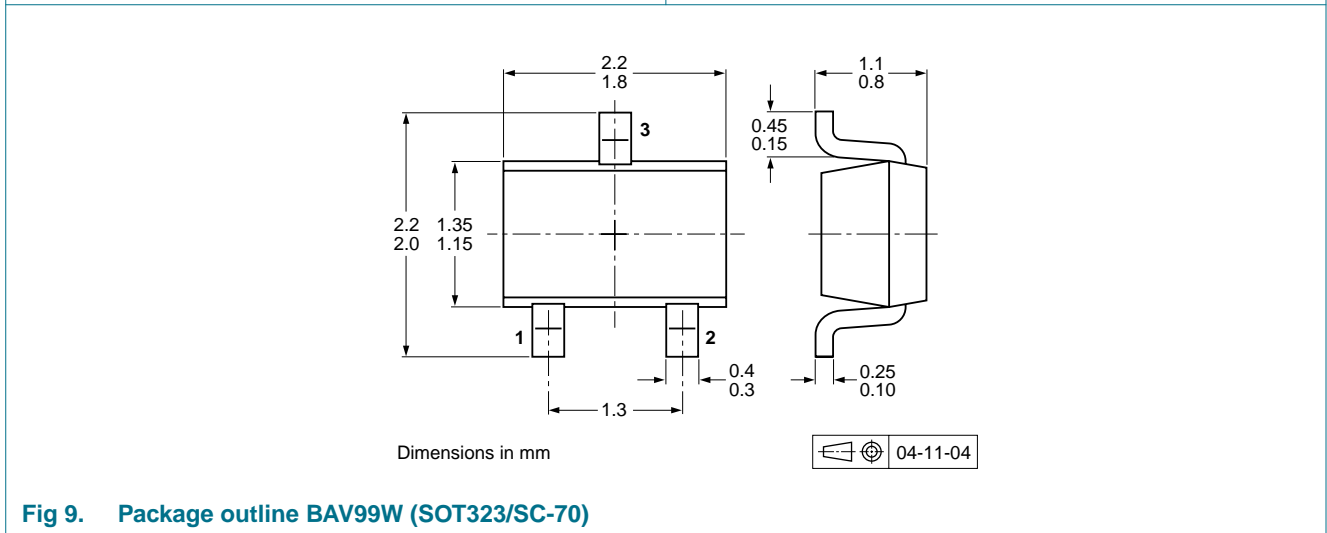
**Fig 6. Forward recovery voltage test circuit and waveforms**

**9. Package outline**



**Fig 7. Package outline BAV99 (SOT23/TO-236AB)**

**Fig 8. Package outline BAV99S (SOT363/SC-88)**



**Fig 9. Package outline BAV99W (SOT323/SC-70)**

**10. Packing information**

**Table 9. Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

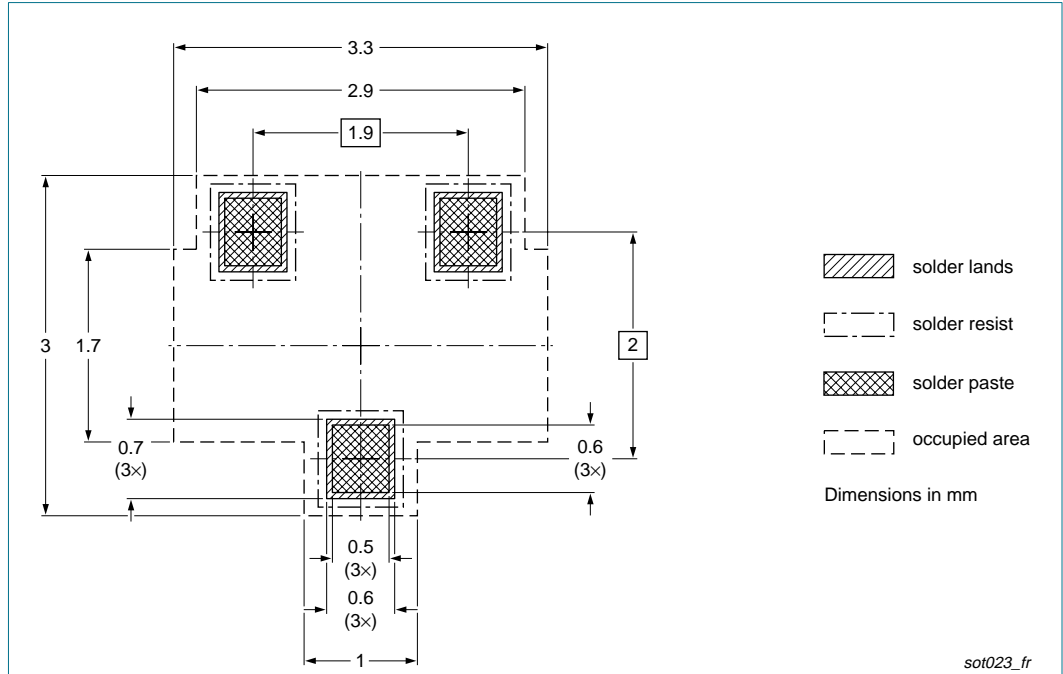
Type number	Package	Description	Packing quantity	
			3000	10000
BAV99	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235
BAV99S	SOT323	4 mm pitch, 8 mm tape and reel	-115	-135
BAV99W	SOT363	4 mm pitch, 8 mm tape and reel; T1	[2] -115	-135
		4 mm pitch, 8 mm tape and reel; T2	[3] -125	-165

[1] For further information and the availability of packing methods, see [Section 14](#).

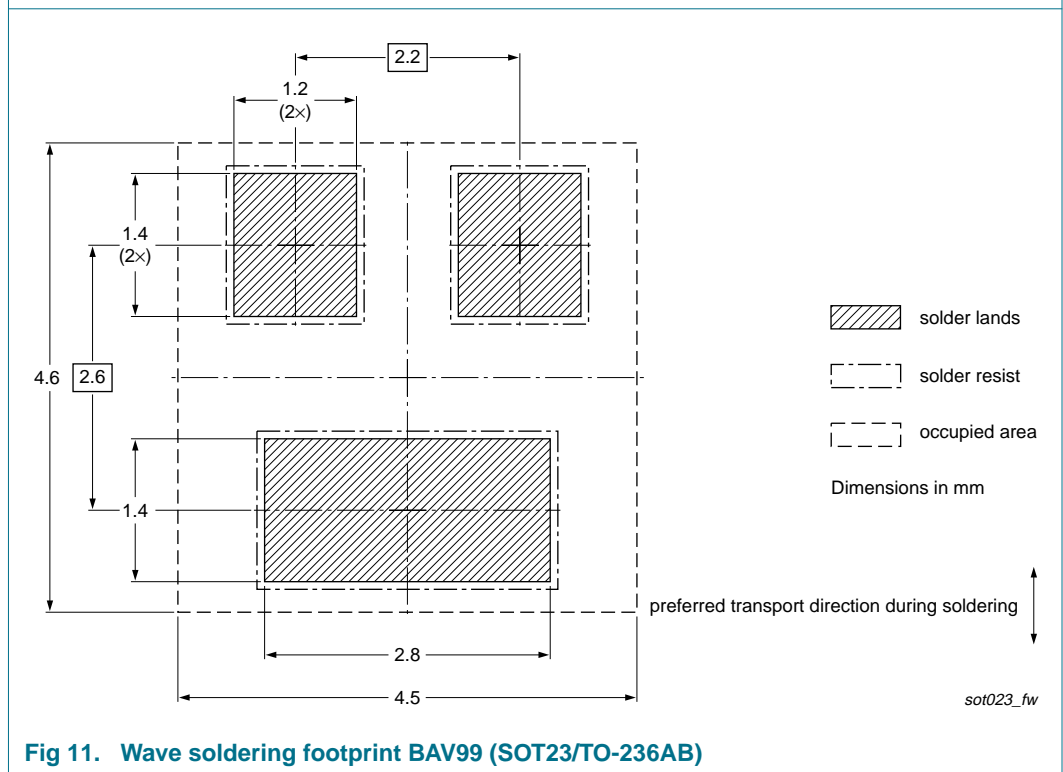
[2] T1: normal taping

[3] T2: reverse taping

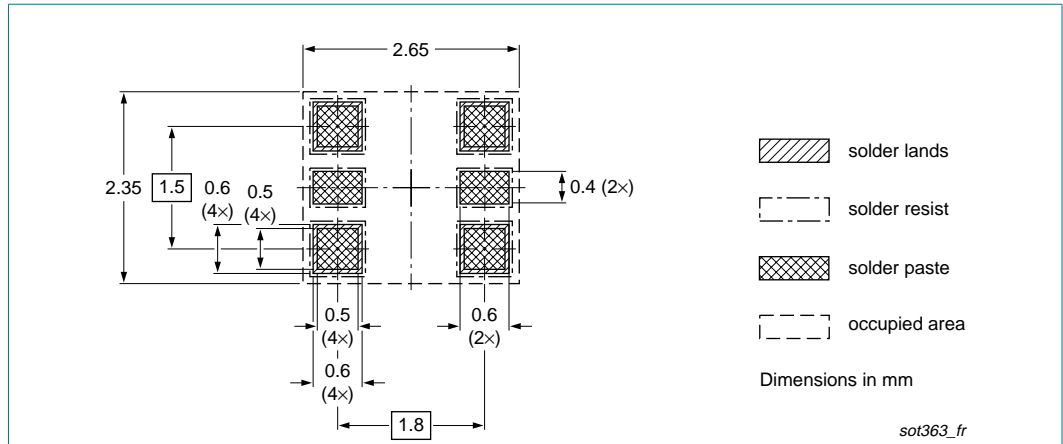
**11. Soldering**



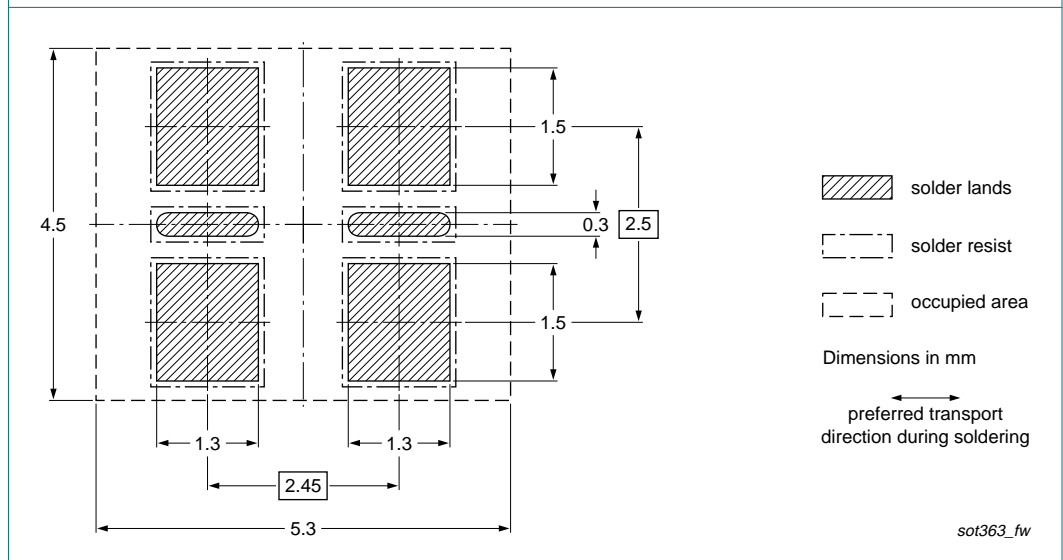
**Fig 10. Reflow soldering footprint BAV99 (SOT23/TO-236AB)**



**Fig 11. Wave soldering footprint BAV99 (SOT23/TO-236AB)**



**Fig 12. Reflow soldering footprint BAV99S (SOT363/SC-88)**



**Fig 13. Wave soldering footprint BAV99S (SOT363/SC-88)**



## 12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAV99_SER_5	20080820	Product data sheet	-	BAV99_4 BAV99S_3 BAV99W_4
Modifications: <ul style="list-style-type: none"> <li>• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>• Legal texts have been adapted to the new company name where appropriate.</li> <li>• <a href="#">Section 1.1 “General description”</a>: amended</li> <li>• <a href="#">Table 1 “Product overview”</a>: added</li> <li>• <a href="#">Table 2 “Quick reference data”</a>: added</li> <li>• <a href="#">Table 6 “Limiting values”</a>: change of <math>V_{RRM}</math> maximum value from 85 V to 100 V</li> <li>• <a href="#">Table 6 “Limiting values”</a>: change of <math>V_R</math> maximum value from 75 V to 100 V</li> <li>• <a href="#">Table 8 “Characteristics”</a>: change of <math>I_R</math> condition <math>V_R</math> from 75 V to 80 V for <math>T_j = 25\text{ °C}</math></li> <li>• <a href="#">Table 8 “Characteristics”</a>: change of <math>I_R</math> maximum value from 1 <math>\mu\text{A}</math> to 0.5 <math>\mu\text{A}</math> for <math>V_R = 80\text{ V}</math> and <math>T_j = 25\text{ °C}</math> condition</li> <li>• <a href="#">Table 8 “Characteristics”</a>: change of <math>I_R</math> condition <math>V_R</math> from 75 V to 80 V for <math>T_j = 150\text{ °C}</math></li> <li>• <a href="#">Section 8 “Test information”</a>: added</li> <li>• <a href="#">Figure 7, 8 and 9</a>: superseded by minimized package outline drawings</li> <li>• <a href="#">Section 10 “Packing information”</a>: added</li> <li>• <a href="#">Section 11 “Soldering”</a>: added</li> <li>• <a href="#">Section 13 “Legal information”</a>: updated</li> </ul>				
BAV99_4	20011015	Product specification	-	BAV99_3
BAV99S_3	20010514	Product specification	-	BAV99S_N_2
BAV99W_4	19990511	Product specification	-	BAV99W_3

## 13. Legal information

### 13.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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